

- CURRENT REGULATOR CHIPS
- ALL JUNCTIONS COMPLETELY PROTECTED WITH SILICON DIOXIDE
- CONSTANT CURRENT OVER WIDE VOLTAGE RANGE
- HIGH SOURCE IMPEDANCE
- COMPATIBLE WITH ALL WIRE BONDING AND DIE ATTACH TECHNIQUES, WITH THE EXCEPTION OF SOLDER REFLOW

CCR250 thru CCR257

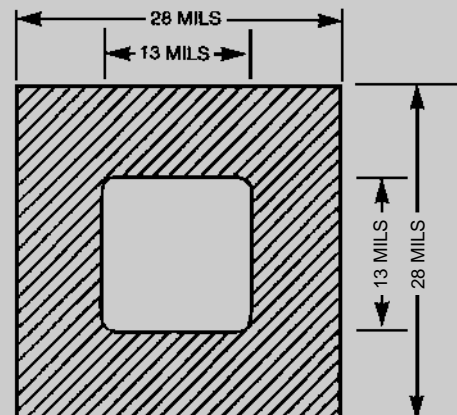
MAXIMUM RATINGS

Operating Temperature: -55°C to +175°C
Storage Temperature: -55°C to +175°C

ELECTRICAL CHARACTERISTICS @ 25°C, unless otherwise specified

TYPE NUMBER	REGULATOR CURRENT I_p (mA) @ $V_S = 25V$			MINIMUM DYNAMIC IMPEDANCE @ $V_S = 25V$ Z_S (K) (Note 2)	MINIMUM KNEE IMPEDANCE @ $V_K = 6.0 V$ Z_K (K) (Note 3)	MAXIMUM LIMITING VOLTAGE @ $I_L = 0.8 I_p$ (min) V_L (VOLTS)	PEAK OPERATING VOLTAGE VOLTS
	NOM	MIN	MAX				
CCR250	5.10	4.59	5.61	100	4.0	3.67	80
CCR251	5.60	5.04	6.16	90	4.0	4.03	80
CCR252	6.20	5.58	6.82	80	3.0	4.46	70
CCR253	6.80	6.12	7.48	70	2.0	4.90	70
CCR254	7.50	6.75	8.25	50	1.5	5.40	60
CCR255	8.20	7.38	9.02	30	1.5	5.90	60
CCR256	9.10	8.19	10.01	20	1.0	6.55	50
CCR257	10.00	9.00	11.10	10	1.0	7.20	50

- NOTE 1** I_p is read using a pulse measurement, 10 milliseconds maximum.
- NOTE 2** Z_S is derived by superimposing A 90Hz RMS signal equal to 10% of V_S on V_S
- NOTE 3** Z_K is derived by superimposing A 90Hz RMS signal equal to 10% of V_K on V_K



Backside is Cathode
A = Anode

DESIGN DATA

- METALLIZATION:**
Top: (Anode).....Al
Back: (Cathode).....Au
- AL THICKNESS**.....25,000 Å Min
- GOLD THICKNESS**4,000 Å Min
- CHIP THICKNESS**10 Mils
- TOLERANCES:** ALL Dimensions
± 2 mils, except Anode Pad where
tolerance is ± 0.1 mils.



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